

STTH120L06TV

Turbo 2 ultrafast high voltage rectifier

Features and benefits

- Ultrafast switching
- Low reverse current
- Low thermal resistance
- Reduces switching and conduction losses

Description

The STTH120L06TV, which is using ST Turbo 2 600 V technology, is specially suited for use in switching power supplies, and industrial applications, as rectification and free-wheeling diode.

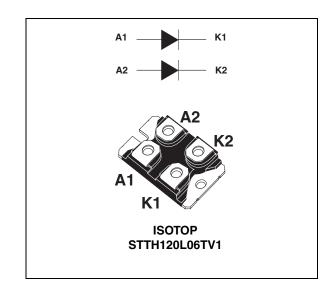


Table 1. Device summary

Symbol	Value
I _{F(AV)}	2 x 60 A
V_{RRM}	600 V
T _j	150 °C
V _F (typ)	0.95 V
t _{rr} (max)	70 ns

TM: ISOTOP is a trademark of STMicroelectronics

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Table 2. Absolute ratings (limiting values, per diode)

Symbol	Parameter	Value	Unit	
V_{RRM}	Repetitive peak reverse voltage	600	V	
I _{F(RMS)}	RMS forward current		120	Α
I _{F(AV)}	Average forward current, $\delta = 0.5$	60	Α	
I _{FSM}	Surge non repetitive forward current	500	Α	
T _{stg}	Storage temperature range	-55 to + 150	°C	
T _j	Maximum operating junction temperat	150	°C	

Table 3. Thermal parameter

Symbol	Parameter		Maximum	Unit
D	Junction to case	Per diode	0.98	
R _{th(j-c)}	Junction to case	Total	0.54	°C/W
R _{th(c)}	Coupling		0.1	

When the diodes 1 and 2 are used simultaneously:

$$\Delta T_{j \text{ (diode1)}} = P_{\text{(diode1)}} x R_{\text{th(j-c) (per diode)}} + P_{\text{(diode2)}} x R_{\text{th(c)}}$$

Table 4. Static electrical characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур	Max.	Unit
I _R ⁽¹⁾	Povorco logizado current	T _j = 25 °C	$V_R = V_{RRM}$			50	μA
'R`	I _R ⁽¹⁾ Reverse leakage current	T _j = 125 °C			50	500	μΑ
V _E (2)	Forward voltage drop	T _j = 25 °C	I _F = 60 A			1.55	V
VF` ′	V _F ⁽²⁾ Forward voltage drop				0.95	1.20	V

^{1.} Pulse test: t_p = 5 ms, δ < 2 %

To evaluate the maximum conduction losses use the following equation:

$$P = 0.93 \text{ x } I_{F(AV)} + 0.0045 I_{F}^{2}_{(RMS)}$$

^{2.} Pulse test: t_p = 380 μ s, δ < 2 %

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 Table 5.
 Dynamic characteristics (per diode)

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
A Deverse receive within a		In = 1 A	I _F = 0.5 A, I _{rr} = 0.25 A, I _R = 1 A			70	ns
t _{rr}	Reverse recovery time	T _j = 25 °C	$I_F = 1 A$, $dI_F/dt = 50 A/\mu s$, $V_R = 30 V$		75	105	119
I _{RM}	Reverse recovery current	T _j = 125 °C	$I_F = 60 \text{ A},$ $dI_F/dt = 400 \text{ A/}\mu\text{s},$ $dI_F/dt = 100 \text{ A/}\mu\text{s}$		14	19	Α
t _{fr}	Forward recovery time	T _j = 25 °C	$I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$			500	ns
V _{FP}	Forward recovery voltage	T _j = 25 °C	$I_F = 60 \text{ A},$ $dI_F/dt = 200 \text{ A/}\mu\text{s}$ $V_{FR} = 1.1 \text{ x } V_{Fmax}$		3		V

Figure 1. Conduction losses versus average Figure 2. Forward voltage drop versus forward current (per diode) forward current (per diode)

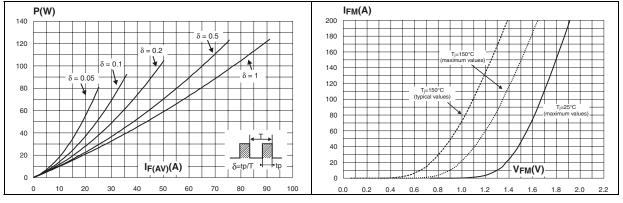
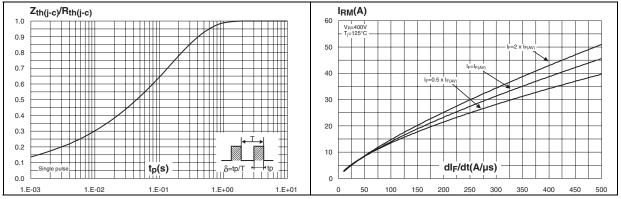


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Peak reverse recovery current versus dl_F/dt (typical values, per diode)



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Figure 5. Reverse recovery time versus dl_F/dt Figure 6. Reverse recovery charges versus dl_F/dt (typical values, per diode)

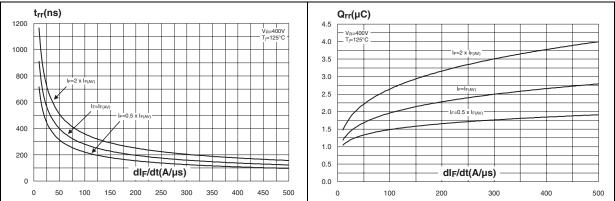


Figure 7. Reverse recovery softness factor versus dl_F/dt (typical values, per diode)

Figure 8. Relative variations of dynamic parameters versus junction temperature

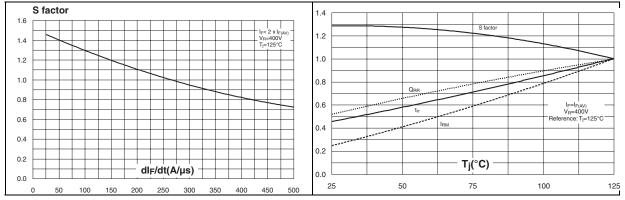
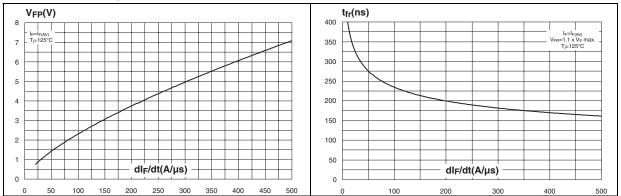


Figure 9. Transient peak forward voltage versus dl_F/dt (typical values, per diode)

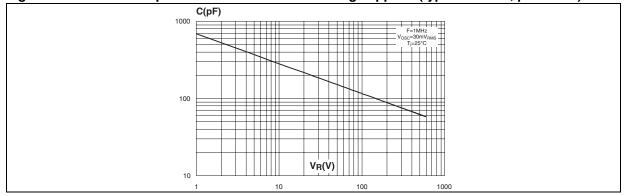
Figure 10. Forward recovery time versus dI_F/dt (typical values, per diode)



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Figure 11. Junction capacitance versus reverse voltage applied (typical values, per diode)



2 Package information

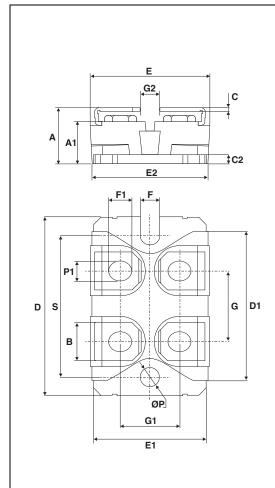
Epoxy meets UL94, V0

Cooling method: by conduction (C)
Recommended torque value: 1.3 N·m

Maximum torque value: 1.5 N⋅m

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Table 6. ISOTOP dimensions



	Dimensions				
Ref.	Millim	Millimeters		hes	
	Min.	Max.	Min.	Max.	
Α	11.80	12.20	0.465	0.480	
A1	8.90	9.10	0.350	0.358	
В	7.8	8.20	0.307	0.323	
С	0.75	0.85	0.030	0.033	
C2	1.95	2.05	0.077	0.081	
D	37.80	38.20	1.488	1.504	
D1	31.50	31.70	1.240	1.248	
Е	25.15	25.50	0.990	1.004	
E1	23.85	24.15	0.939	0.951	
E2	24.80 typ.		0.97	6 typ.	
G	14.90	15.10	0.587	0.594	
G1	12.60	12.80	0.496	0.504	
G2	3.50	4.30	0.138	0.169	
F	4.10	4.30	0.161	0.169	
F1	4.60	5.00	0.181	0.197	
Р	4.00	4.30	0.157	0.69	
P1	4.00	4.40	0.157	0.173	
S	30.10	30.30	1.185	1.193	

3 Ordering information

Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
STTH120L06TV1	STTH120L06TV1	ISOTOP	27 g (without screws)	10 (with screws)	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes	
07-Sep-2004	1	First issue.	
04-Apr-2011	2	Updated Chapter 2: Package information.	

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